

August 1995

54F/74F280 9-Bit Parity Generator/Checker

General Description

Features

The 'F280 is a high-speed parity generator/checker that accepts nine bits of input data and detects whether an even or an odd number of these inputs is HIGH. If an even number of inputs is HIGH, the Sum Even output is HIGH. If an odd number is HIGH, the Sum Even output is LOW. The Sum Odd output is the complement of the Sum Even output.

■ Guaranteed 4000V minimum ESD protection

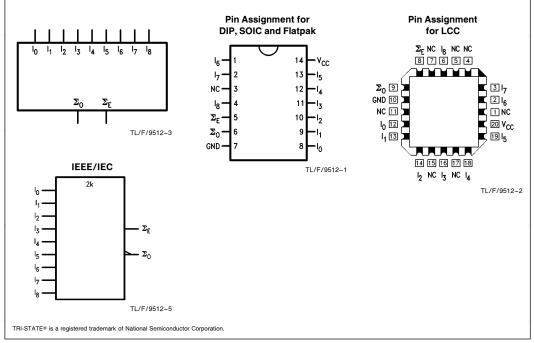
Commercial	Military	Package Number	Package Description	
74F280PC		N14A	14-Lead (0.300" Wide) Molded Dual-In-Line	
	54F280DM (Note 2)	J14A	14-Lead Ceramic Dual-In-Line	
74F280SC (Note 1)		M14A	14-Lead (0.150" Wide) Molded Small Outline, JEDEC	
74F280SJ (Note 1)		M14D	14-Lead (0.300" Wide) Molded Small Outline, EIAJ	
	54F280FM (Note 2)	W14B	14-Lead Cerpack	
	54F280LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C	

Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

Logic Symbols

Connection Diagrams



© 1995 National Semiconductor Corporation TL/F/9512

RRD-B30M115/Printed in U. S. A.

Unit Loading/Fan Out

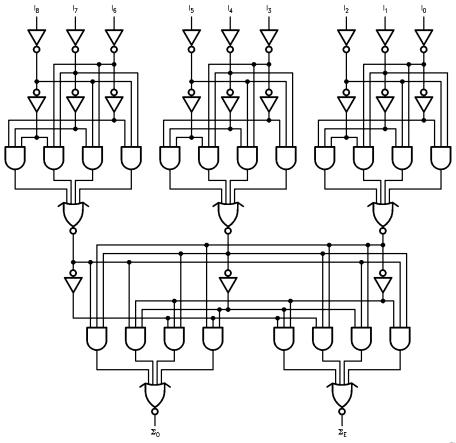
		54F/74F				
Pin Names Description		U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}			
I ₀ -I ₈	Data Inputs	1.0/1.0	20 μA/-0.6 mA			
Σ_{O}	Odd Parity Output	50/33.3	-1 mA/20 mA			
Σ_{E}	Even Parity Output	50/33.3	-1 mA/20 mA			

Truth Table

Number of	Outputs				
HIGH Inputs I ₀ –I ₈	Σ Even	Σ Odd			
0, 2, 4, 6, 8	Н	L			
1, 3, 5, 7, 9	L	Н			

H = HIGH Voltage Level L = LOW Voltage Level

Logic Diagram



TL/F/9512-4

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \text{Storage Temperature} & -65^{\circ}\text{C to} + 150^{\circ}\text{C} \\ \text{Ambient Temperature under Bias} & -55^{\circ}\text{C to} + 125^{\circ}\text{C} \\ \text{Junction Temperature under Bias} & -55^{\circ}\text{C to} + 175^{\circ}\text{C} \\ \text{Plastic} & -55^{\circ}\text{C to} + 150^{\circ}\text{C} \\ \end{array}$

V_{CC} Pin Potential to

Voltage Applied to Output

in HIGH State (with $V_{CC} = 0V$)

 $\begin{array}{ll} \mbox{Standard Output} & -0.5\mbox{V to V}_{\mbox{CC}} \\ \mbox{TRI-STATE} \mbox{$^{\circ}$ Output} & -0.5\mbox{V to } +5.5\mbox{V} \end{array}$

Current Applied to Output in LOW State (Max) twice ESD Last Passing Voltage (Min)

twice the rated I_{OL} (mA) 4000V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature

Military $-55^{\circ}\text{C to} + 125^{\circ}\text{C}$ Commercial $0^{\circ}\text{C to} + 70^{\circ}\text{C}$

Supply Voltage

Military +4.5V to +5.5V Commercial +4.5V to +5.5V

DC Electrical Characteristics

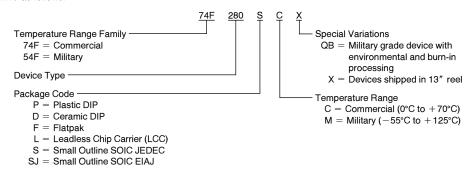
Symbol	Parameter		54F/74F			Units	v _{cc}	Conditions	
Symbol			Min	Тур	Max	Oilles	VCC	Conditions	
V _{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal		
V _{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal		
V_{CD}	Input Clamp Diode Vo	oltage			-1.2	V	Min	$I_{\text{IN}} = -18 \text{ mA}$	
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC}	2.5 2.5 2.7			٧	Min	$I_{OH} = -1 \text{ mA}$ $I_{OH} = -1 \text{ mA}$ $I_{OH} = -1 \text{ mA}$	
V _{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}			0.5 0.5	٧	Min	I _{OL} = 20 mA I _{OL} = 20 mA	
I _{IH}	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	V _{IN} = 2.7V	
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V _{IN} = 7.0V	
I _{CEX}	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	$V_{OUT} = V_{CC}$	
V _{ID}	Input Leakage Test	74F	4.75			٧	0.0	$I_{\text{ID}} = 1.9 \mu\text{A}$ All Other Pins Grounded	
I _{OD}	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V _{IOD} = 150 mV All Other Pins Grounded	
I _{IL}	Input LOW Current				-0.6	mA	Max	V _{IN} = 0.5V	
los	Output Short-Circuit (-60		-150	mA	Max	$V_{OUT} = 0V$		
Icch	Power Supply Curren		25	38	mA	Max	V _O = HIGH		

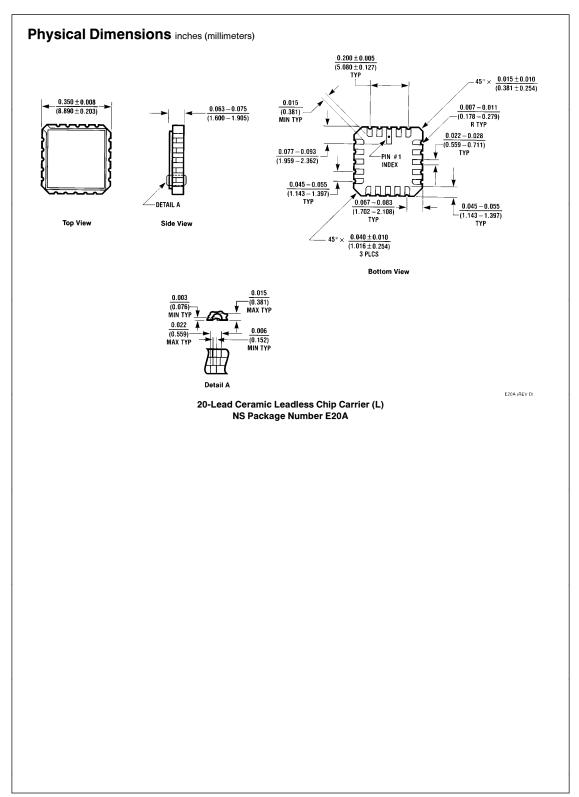
AC Electrical Characteristics

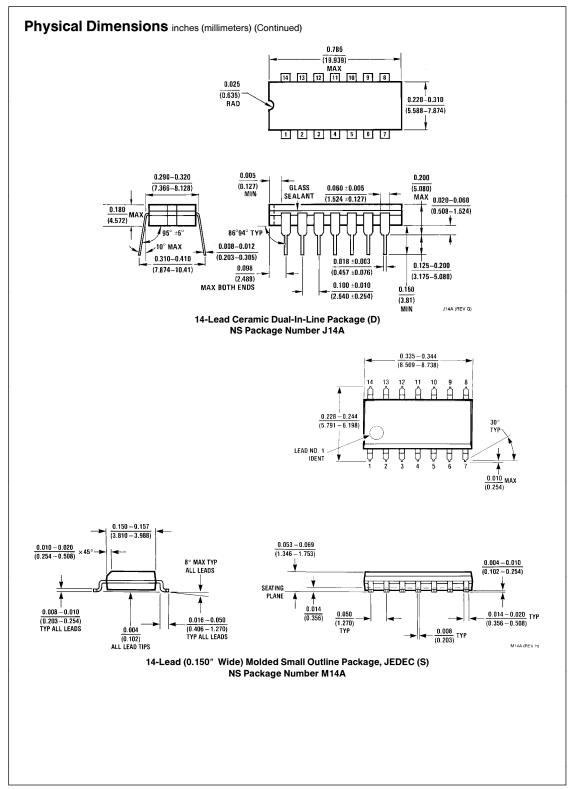
Symbol	Parameter	$74F$ $T_A = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_L = 50 \text{ pF}$			54F		74F		Units
					$ extsf{T}_{ extsf{A}}, extsf{V}_{ extsf{CC}} = extsf{Mil} \ extsf{C}_{ extsf{L}} = extsf{50 pF}$		T _A , V _{CC} = Com C _L = 50 pF		
		Min	Тур	Max	Min	Max	Min	Max	
t _{PLH}	Propagation Delay I_n to Σ_E	6.5 6.5	10.0 11.0	15.0 16.0	6.5 6.5	20.0 21.0	6.5 6.5	16.0 17.0	ns
t _{PLH}	Propagation Delay I_n to Σ_O	6.0 6.5	10.0 11.0	15.0 16.0	5.0 6.5	20.0 21.0	6.0 6.5	16.0 17.0	ns

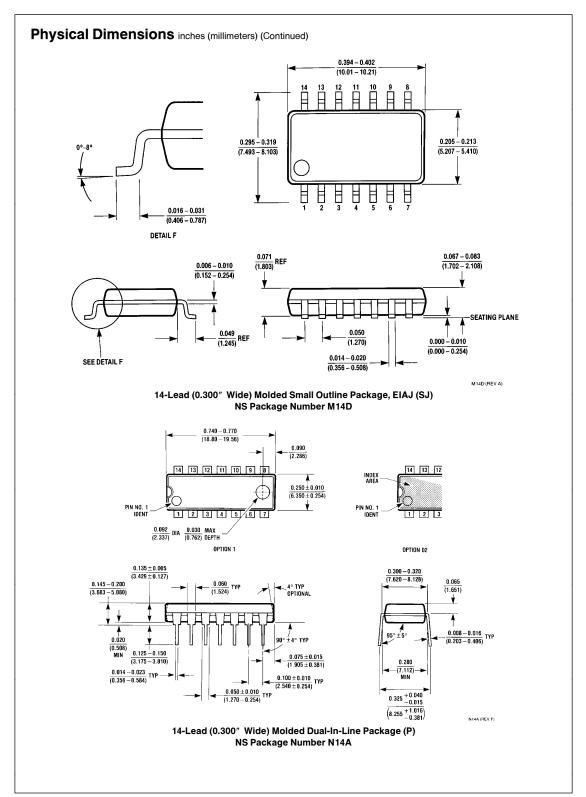
Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

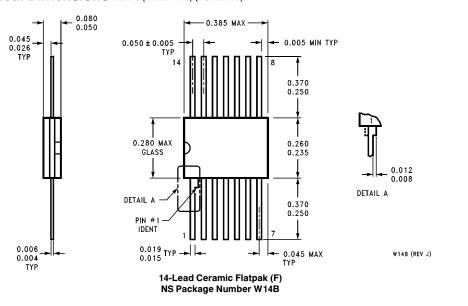








Physical Dimensions inches (millimeters) (Continued)



LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation 1111 West Bardin Road Arlington, TX 76017 Tel: 1(800) 272-9959 Fax: 1(800) 737-7018 National Semiconductor Europe

Fax: (+49) 0-180-530 85 86 Email: cnjwge@tevm2.nsc.com Deutsch Tel: (+49) 0-180-530 85 85 English Tel: (+49) 0-180-532 78 32 Français Tel: (+49) 0-180-532 93 58 Italiano Tel: (+49) 0-180-534 16 80 National Semiconductor Hong Kong Ltd. 13th Floor, Straight Block, Ocean Centre, 5 Canton Rd. Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960 National Semiconductor Japan Ltd. Tel: 81-043-299-2309 Fax: 81-043-299-2408

National does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and National reserves the right at any time without notice to change said circuitry and specifications